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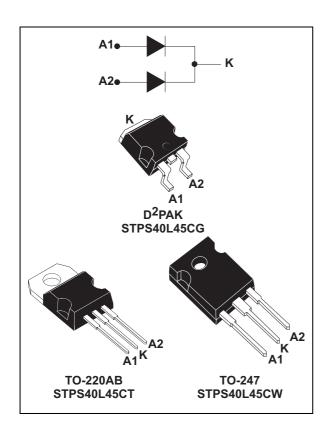


STPS40L45C



Low drop power Schottky rectifier

Datasheet - production data



Description

Dual center tap Schottky barrier rectifier designed for high frequency switched mode power supplies and DC to DC converters.

Packaged in TO-220AB, TO-247 and D²PAK these devices are intended for use in low voltage,

high frequency inverters, free-wheeling and polarity protection applications.

Table 1. Device summary

| $I_{F(AV)}$ | 2 x 20 A |
|----------------------|----------|
| V_{RRM} | 45 V |
| T _j (max) | 150° C |
| V _F (max) | 0.49 V |

Features

- Low forward voltage drop meaning very small conduction losses
- Low switching losses allowing high frequency operation
- · Avalanche capability specified

Characteristics STPS40L45C

1 Characteristics

Table 2. Absolute Ratings (limiting values, per diode)

| Symbol | Paramet | Value | Unit | | |
|---------------------|---|-------|----------|--------------|------|
| V_{RRM} | Repetitive peak reverse voltage | | | 45 | V |
| I _{F(RMS)} | Forward rms current | | | 30 | Α |
| I _{F(AV)} | | | 20 40 | Α | |
| I _{FSM} | Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$ | | | 220 | Α |
| I _{RRM} | Repetitive peak reverse current $t_p = 2 \mu s \text{ square } F = 1 \text{ kHz}$ | | | 2 | Α |
| I _{RSM} | Non repetitive peak reverse current $t_p = 100 \mu s$ square | | | 3 | Α |
| P _{ARM} | Repetitive peak avalanche power $t_p = 1 \mu s T_j = 25^{\circ} C$ | | | 8100 | W |
| T _{stg} | Storage temperature range | | | -65 to + 150 | °C |
| Tj | Maximum operating junction temperature (1) | | | 150 | °C |
| dV/dt | Critical rate of rise of reverse voltage | | | 10000 | V/µs |

^{1.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

| Symbol | Parameter | Value | Unit | |
|-----------------------|------------------|--------------------|------------|------|
| R _{th (j-c)} | Junction to case | Per diode Total | 1.5 0.8 | °C/W |
| R _{th(c)} | Coupling | | 0.1 | °C/W |

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_j(diode\ 1) = P(diode\ 1)\ x\ R_{th(j\text{-}c)}(Per\ diode)\ +\ P(diode\ 2)\ x\ R_{th(c)}.$

Table 4. Static electrical characteristics (per diode)

| Symbol | Parameter | Test Conditions | | Min. | Тур. | Max. | Unit |
|-------------------------------|-------------------------|-------------------------|-----------------------|------|------|------|------|
| I _B ⁽¹⁾ | Reverse leakage current | T _j = 25° C | $V_R = V_{RRM}$ | | | 0.6 | mA |
| 'R` | | T _j = 125° C | | | 140 | 280 | mA |
| | Forward voltage drop | T _j = 25° C | I _F = 20 A | | | 0.53 | |
| V _E (1.) | | T _j = 125° C | I _F = 20 A | | 0.42 | 0.49 | V |
| v F.7. | | T _j = 25° C | I _F = 40 A | | | 0.69 | V |
| | | T _j = 125° C | I _F = 40 A | | 0.6 | 0.7 | |

^{1.} Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.28 \times I_{F(AV)} + 0.0105 I_{F}^{2}_{(RMS)}$$



STPS40L45C **Characteristics**

Figure 1. Average forward power dissipation versus average forward current (per diode)

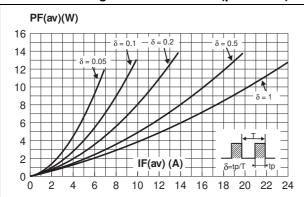
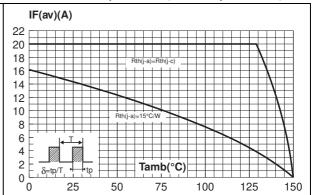


Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode)



versus pulse duration

Figure 3. Normalized avalanche power derating Figure 4. Normalized avalanche power derating versus junction temperature

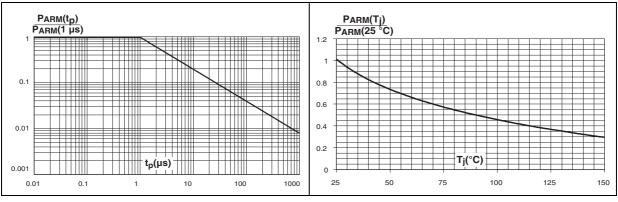
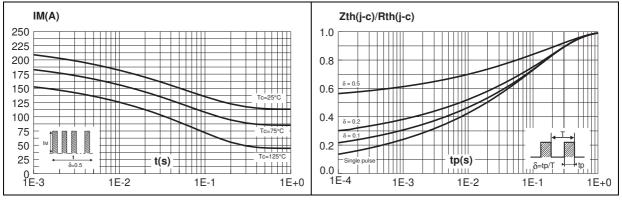


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

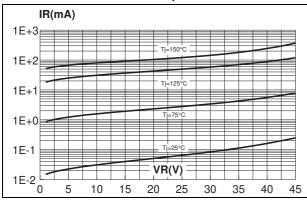
Figure 6. Relative variation of thermal impedance junction to case versus pulse duration



Characteristics STPS40L45C

Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)



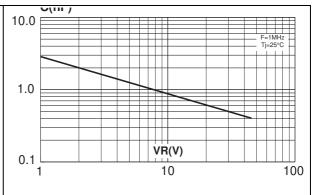
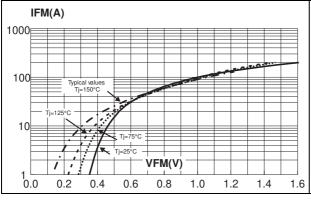
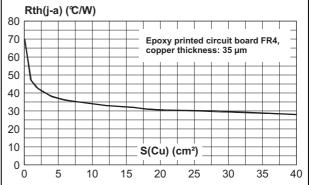


Figure 9. Forward voltage drop versus forward current (maximum values, per diode)

Figure 10. Thermal resistance junction to ambient versus copper surface under tab





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2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m (TO-220AB)
- Recommended torque value: 0.55, 1.0 N·m maximum (TO-247)

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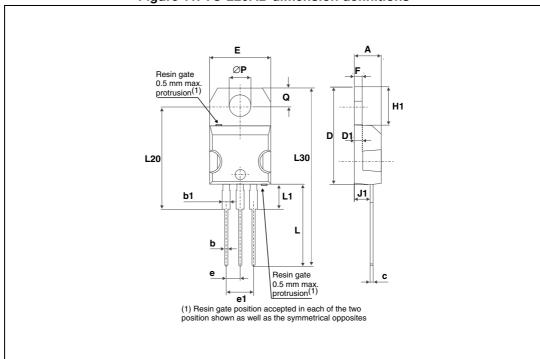


Figure 11. TO-220AB dimension definitions

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Table 5. TO-220AB dimension values

| | Dimensions | | | | | |
|------|------------|-------------|-----------|-------|--|--|
| Ref. | Millim | Millimeters | | hes | | |
| | Min. | Max. | Min. | Max. | | |
| Α | 4.40 | 4.60 | 0.17 | 0.18 | | |
| b | 0.61 | 0.88 | 0.024 | 0.035 | | |
| b1 | 1.14 | 1.70 | 0.045 | 0.067 | | |
| С | 0.48 | 0.70 | 0.019 | 0.027 | | |
| D | 15.25 | 15.75 | 0.60 | 0.62 | | |
| D1 | 1.27 typ. | | 0.05 | typ. | | |
| E | 10 | 10.40 | 0.39 | 0.41 | | |
| е | 2.40 | 2.70 | 0.094 | 0.106 | | |
| e1 | 4.95 | 5.15 | 0.19 | 0.20 | | |
| F | 1.23 | 1.32 | 0.048 | 0.052 | | |
| H1 | 6.20 | 6.60 | 0.24 | 0.26 | | |
| J1 | 2.40 | 2.72 | 0.094 | 0.107 | | |
| L | 13 | 14 | 0.51 | 0.55 | | |
| L1 | 3.50 | 3.93 | 0.137 | 0.154 | | |
| L20 | 16.40 typ. | | 0.64 typ. | | | |
| L30 | 28.90 typ. | | 1.13 | typ. | | |
| ØP | 3.75 | 3.85 | 0.147 | 0.151 | | |
| Q | 2.65 | 2.95 | 0.104 | 0.116 | | |

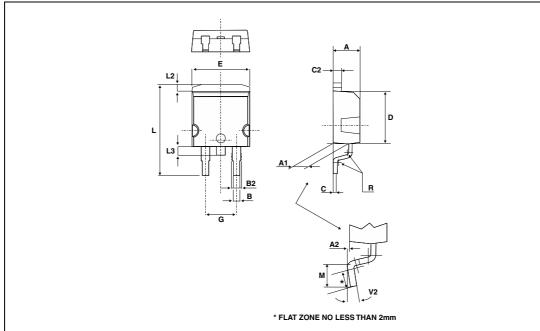


Figure 12. D²PAK dimension definitions

Table 6. D²PAK dimension values

| | | Dime | nsions | |
|------|--------|-----------|--------|--------|
| Ref. | Millin | neters | Inc | hes |
| | Min. | Max. | Min. | Max. |
| Α | 4.40 | 4.60 | 0.173 | 0.181 |
| A1 | 2.49 | 2.69 | 0.098 | 0.106 |
| A2 | 0.03 | 0.23 | 0.001 | 0.009 |
| В | 0.70 | 0.93 | 0.027 | 0.037 |
| B2 | 1.14 | 1.70 | 0.045 | 0.067 |
| С | 0.45 | 0.60 | 0.017 | 0.024 |
| C2 | 1.23 | 1.36 | 0.048 | 0.054 |
| D | 8.95 | 9.35 | 0.352 | 0.368 |
| Е | 10.00 | 10.40 | 0.393 | 0.409 |
| G | 4.88 | 5.28 | 0.192 | 0.208 |
| L | 15.00 | 15.85 | 0.590 | 0.624 |
| L2 | 1.27 | 1.40 | 0.050 | 0.055 |
| L3 | 1.30 | 1.75 | 0.051 | 0.069 |
| М | 2.29 | 2.79 | 0.090 | 0.110 |
| R | 0.40 | 0.40 typ. | | 6 typ. |
| V2 | 0° | 8° | 0° | 8° |

Package Information STPS40L45C

Figure 13. D²PAK footprint (dimensions in mm)

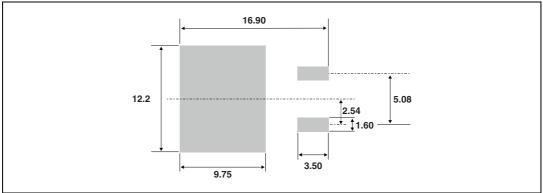


Figure 14. TO-247 dimension definitions

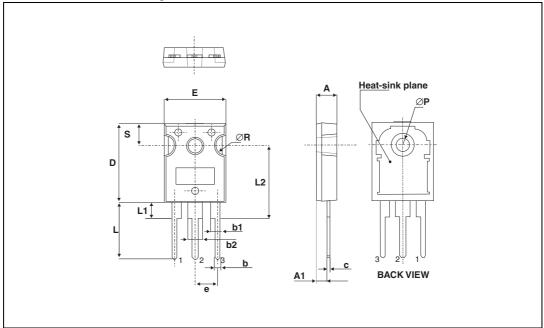


Table 7. TO-247 dimension values

| | Dimensions | | | | | |
|-------------------|------------|-------------|-------|------------|--------|-------|
| Ref. | | Millimeters | | | Inches | |
| | Min. | Тур. | Max. | Min. | Тур | Max. |
| А | 4.85 | | 5.15 | 0.191 | | 0.203 |
| A1 | 2.20 | | 2.60 | 0.086 | | 0.102 |
| b | 1.00 | | 1.40 | 0.039 | | 0.055 |
| b1 | 2.00 | | 2.40 | 0.078 | | 0.094 |
| b2 | 3.00 | | 3.40 | 0.118 | | 0.133 |
| С | 0.40 | | 0.80 | 0.015 | | 0.031 |
| D ⁽¹⁾ | 19.85 | | 20.15 | 0.781 | | 0.793 |
| E | 15.45 | | 15.75 | 0.608 | | 0.620 |
| е | 5.30 | 5.45 | 5.60 | 0.209 | 0.215 | 0.220 |
| L | 14.20 | | 14.80 | 0.559 | | 0.582 |
| L1 | 3.70 | | 4.30 | 0.145 | | 0.169 |
| L2 | 18.50 typ. | | | 0.728 typ. | | |
| ØP ⁽²⁾ | 3.55 | | 3.65 | 0.139 | | 0.143 |
| ØR | 4.50 | | 5.50 | 0.177 | | 0.217 |
| S | 5.30 | 5.50 | 5.70 | 0.209 | 0.216 | 0.224 |

^{1.} Dimension D plus gate protrusion does not exceed 20.5 mm

^{2.} Resin thickness around the mounting hole is not less than 0.9 \mbox{mm}

Ordering Information STPS40L45C

3 Ordering Information

Table 8. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|-------------|-------------|--------------------|--------|----------|---------------|
| STPS40L45CG | STPS40L45CG | D ² PAK | 1.8g | 500 | Tape and reel |
| STPS40L45CT | STPS40L45CT | TO-220AB | 2g | 50 | Tube |
| STPS40L45CW | STPS40L45CW | TO-247 | 4.4g | 30 | Tube |

4 Revision history

Table 9. Document revision history

| Date | Revision | Description of Changes |
|-------------|----------|-------------------------------------|
| Jul-2003 | 4A | Previous version |
| 30-Oct-2013 | 5 | Updated Package information section |

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